

# isc N-Channel MOSFET Transistor

## FDB5800

#### **FEATURES**

- Drain Current : I<sub>D</sub>=14A@ T<sub>C</sub>=25℃
- Drain Source Voltage
  - : V<sub>DSS</sub>= 60V(Min)
- Static Drain-Source On-Resistance
  - :  $R_{DS(on)}$  =6m  $\Omega$  (Max) @  $V_{GS}$ = 10V
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

## **DESCRIPTION**

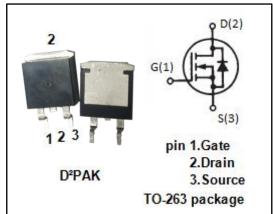
 motor drive, DC-DC converter, power switch and solenoid drive.

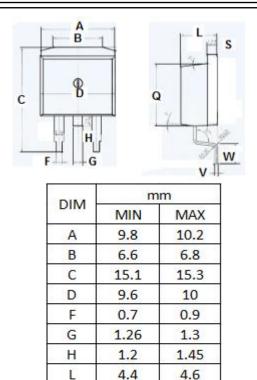
## ABSOLUTE MAXIMUM RATINGS(T<sub>a</sub>=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V <sub>DSS</sub>	Drain-Source Voltage	60	V
V <sub>GSS</sub>	Gate-Source Voltage	±20	V
I <sub>D</sub>	Drain Current-Continuous;@Tc=25℃	14	А
I <sub>DM</sub>	Drain Current-Single Pulsed	56	А
$P_D$	Total Dissipation	242	W
T <sub>j</sub>	Operating Junction Temperature	-55~175	$^{\circ}$
T <sub>stg</sub>	Storage Temperature	-55~175	$^{\circ}$

#### • THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
Rth(ch-c)	Channel-to-case thermal resistance	0.62	°C/W





9.2

1.25

0.4

2.6

9.3

1.35

0.6

2.8

Q

S

V

W



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#### **ELECTRICAL CHARACTERISTICS**

Tc=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> = 0.25mA	60	-	-	V
V <sub>GS(th)</sub>	Gate Threshold Voltage	$V_{DS}$ = $V_{GS}$ ; $I_D$ = 0.25mA	1	-	2.5	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> =10V; I <sub>D</sub> =80A	-	-	6	mΩ
I <sub>GSS</sub>	Gate-Source Leakage Current	$V_{GS}$ = $\pm 20V; V_{DS}$ = $0V$	-	-	±100	nA
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> =48V; V <sub>GS</sub> = 0V	-	-	1	uA
V <sub>SD</sub>	Diode forward voltage	I <sub>SD</sub> =80A, V <sub>GS</sub> = 0 V	-	-	1.25	V

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